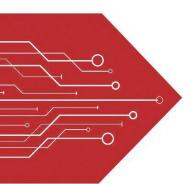
MSKSEMI















ESD

TVS

TSS

MOV

GDT

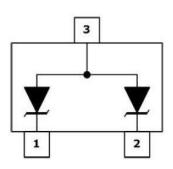
PLED

Broduct data sheet



PIN CONFIGURATION





SOT-23

FEATURES

- SOT-23 package allows either two separate unidirectional configurations or a single bidirectional configuration.
- Working peak reverse voltage 3V to 22V
- Standard Zener breakdown voltage 5.6V to 27V
- Peak power 24 or 40 Watts @ 1.0ms (unidirectional) per Figure 6 Waveform
- ESD Rating: Class 3B (>16kV) per the Human Body Model Class C (>400V) per Machine Model
- ESD Rating of IEC61000-4-2 level 4, ±30kV contact Discharge
- Low leakage < 5.0µA

MACHANICAL DATA

- SOT-23 package
- Flammability Rating: UL 94V-0
- Packaging: Tape and Reel
- High temperature soldering guaranted:260 ℃/10s
- Reel size: 7 inch

APPLICATIONS

- Computers
- Printers
- Business Machines
- Communication systems
- Medical equipment

ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Units
	Peak Power Dissipation @1.0ms		
P _{PK}	MMBZ5V6AL-MS thru MMBZ9V1AL-MS	24	W
	MMBZ12VAL-MS thru MMBZ27VAL-MS	40	
P _D	Total Power Dissipation	200	mW
T _{OPT}	Operating Temperature	-55/+150	°C
T _{STG}	Storage Temperature	-55/+150	°C

24 WATTS ELECTRICAL CHARACTERISTICS (Tamb=25°C) UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or Pins 2 to 3)

		V_{RWM}	I_R	V_{BR}				Z _{ZT}	Z_{ZK}		Vc	
P/N	Marking	(V)	(μΑ)		(V)		(mA)	(Ω)	(Ω)	(mA)	(V)	(A)
	Iviaikiig		@	Min	Nom	Max	@	Max	Max	@	Max	@
			V_{RWM}	IVIIII	NOIII	IVIAX	Ιτ	@I _{ZT}	IVIAX	I_{ZK}	ividX	I_{PP}
MMBZ5V6ALT1G-MS	5A6+code	3.0	5.0	5.32	5.6	5.88	20	11	1600	0.25	8.0	3.0
MMBZ6V2ALT1G-MS	6A2+code	3.0	0.5	5.89	6.2	6.51	1.0				8.7	2.76
MMBZ6V8ALT1G-MS	6A8+code	4.5	0.5	6.46	6.8	7.14	1.0				9.6	2.5
MMBZ9V1ALT1G-MS	9A1+code	6.0	0.3	8.65	9.1	9.56	1.0				14	1.7

V_F=0.9V Max @ I_F=10mA

40 WATTS ELECTRICAL CHARACTERISTICS (Tamb=25°C) UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or Pins 2 to 3)

	V _{RWM} I _R V _{BR}				V _C (note1)				
	(V)		(nA)	(V)			(mA)	(V)	(A)
P/N	Marking		@	Min	Nom	Max	@	Max	@
			V_{RWM}				Ι _Τ		I _{PP}
MMBZ12VALT1G-MS	12A+code	8.5	200	11.40	12	12.60	1	17	2.35
MMBZ15VALT1G-MS	15A+code	12.0	50	14.25	15	15.75	1	21	1.90
MMBZ18VALT1G-MS	18A+code	14.5	50	17.10	18	18.90	1	25	1.60
MMBZ20VALT1G-MS	20A+code	16.0	50	19	20	21	1	38	1.0
MMBZ27VALT1G-MS	27A+code	22.0	50	25.65	27	28.35	1	40	1.0

V_F=0.9V Max @ I_F=10mA

Note 1: Surge Current waveform per Figure 5

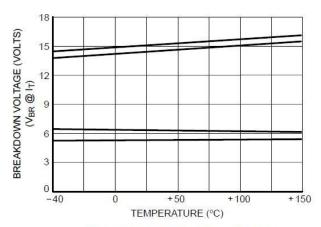


Figure 1. Typical Breakdown Voltage versus Temperature

(Upper curve for each voltage is bidirectional mode, lower curve is unidirectional mode)

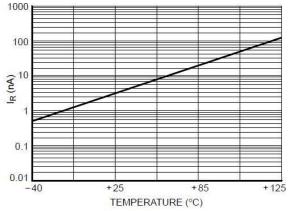


Figure 2. Typical Leakage Current versus Temperature

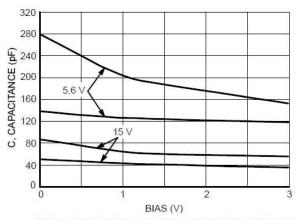


Figure 3. Typical Capacitance versus Bias Voltage (Upper curve for each voltage is unidirectional mode, lower curve is bidirectional mode)

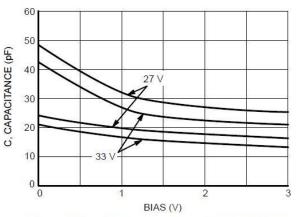


Figure 4. Typical Capacitance versus Bias Voltage (Upper curve for each voltage is unidirectional mode, lower curve is bidirectional mode)

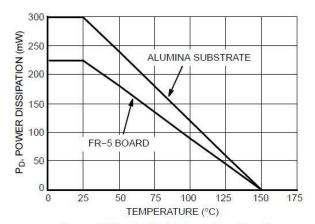
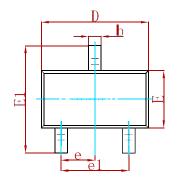
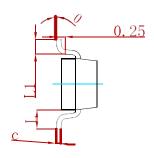


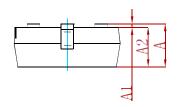
Figure 5. Steady State Power Derating Curve



PACKAGE MECHANICAL DATA

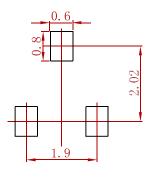






Comphal	Dimensions	s In Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
Α	0.900	1.150	0.035	0.045		
A1	0.000	0.100	0.000	0.004		
A2	0.900	1.050	0.035	0.041		
b	0.300	0.500	0.012	0.020		
С	0.080	0.150	0.003	0.006		
D	2.800	3.000	0.110	0.118		
E	1.200	1.400	0.047	0.055		
E1	2.250	2.550	0.089	0.100		
е	0.950) TYP	0.03	7 TYP		
e1	1.800	2.000	0.071	0.079		
L	0.55	0 REF	0.02	2 REF		
L1	0.300	0.500	0.012	0.020		
θ	0°	8°	0°	8°		

Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters. 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
MMBZXXXALT1G-MS	SOT-23	3000



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